

TO-220-3L Plastic-Encapsulate Diode

MUR20H20CT HYPERFAST RECTIFIER, FRED

MAIN CHARACTERISTICS

I_o	20(10×2)A
V_{RRM}	200V
T_{rr}	14ns
T_j	175℃
$V_{F(typ)}$	0.8V(@ $T_j=150℃$)

FEATURES

- Ultrafast Recovery Times and Low Recovery Loss
- Low Forward Voltage
- Low Reverse Leakage Current

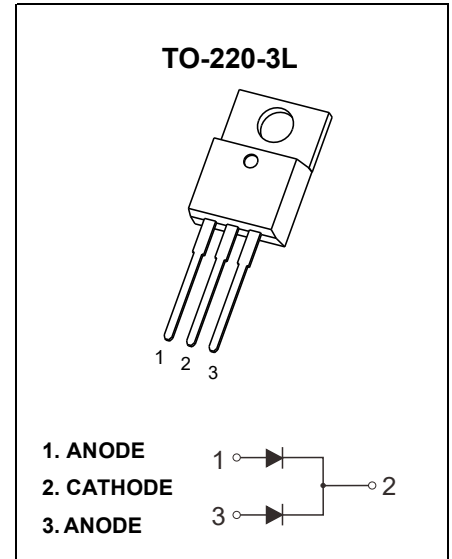
APPLICATIONS

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MARKING



MUR20H20CT = Device code
Solid dot = Green molding compound device
if none, the normal device
XXXX = Code



MAXIMUM RATINGS ($T_c=25℃$ unless otherwise noted)

Symbol	Parameter	MUR20H20CT	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	200	V
V_R	DC Blocking Voltage		
$I_{F(AV)}$	Average rectified output current@ Per leg($T_c=148℃$)	10	A
	Average rectified output current@ Total device($T_c=148℃$)	20	
$I_{F(RMS)}$	RMS Forward Current($T_c=148℃$)	14	A
I_{FSM}	Non-Repetitive Surge Forward Current (8.3ms)	165	A
P_D	Power dissipation	43	W
$R_{\theta JC}$	Thermal Resistance From Junction to Case@ Per leg	3.5	℃/W
T_j	Operating Junction Temperature Range	-55 ~ +175	℃
T_{stg}	Storage Temperature Range	-55 ~ +175	℃

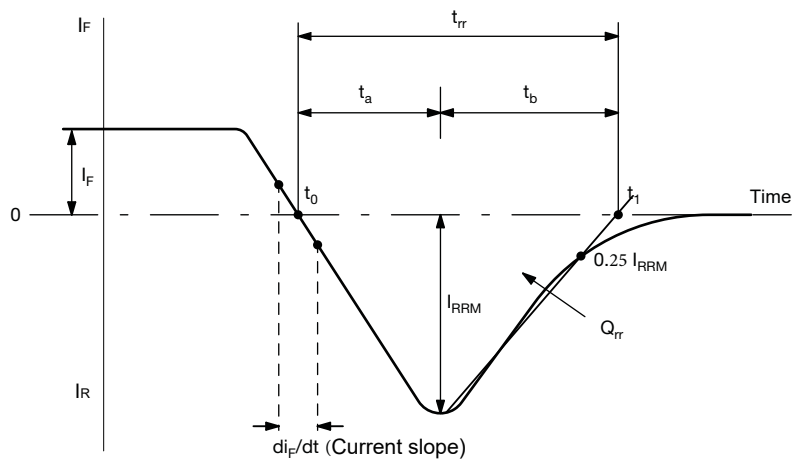
Typical Characteristics

ELECTRICAL CHARACTERISTICS ($T_c=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{(BR)}$	Reverse Voltage	$I_R=100\mu\text{A}$	200			V
I_R	Reverse Current	$V_R=200\text{V}$			5	μA
					500	μA
V_F	Forward Voltage	$I_F=10\text{A}$		0.9	1.1	V
				0.8		V
C_{tot}	Total Capacitance	$V_R=200\text{V}, f=1\text{MHz}$		24		pF
t_{rr}	Reverse Recovery time	$I_F=0.5\text{A}, I_R=1\text{A}, I_{rr}=0.25\text{A}$		17		ns
		$I_F=1\text{A}, V_R=30\text{V}, di_F/dt = 200\text{A/us}$		14		ns

ELECTRICAL CHARACTERISTICS ($T_c=25^{\circ}\text{C}$ unless otherwise specified)

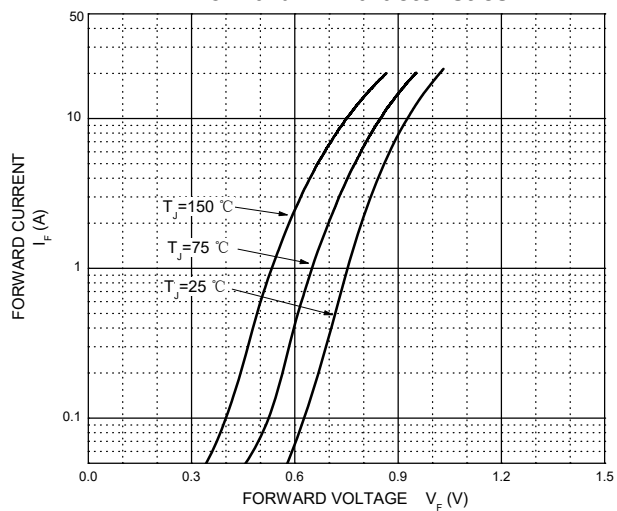
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
t_{rr}	Reverse Recovery Time	$I_F=10\text{A}, V_R=100\text{V}, di_F/dt=200\text{A}/\mu\text{s}$		19		ns
I_{RRM}	Max. Reverse Recovery Current			4		A
Q_{rr}	Reverse Recovery Charge			34		nC
t_{rr}	Reverse Recovery Time	$I_F=10\text{A}, V_R=100\text{V}, di_F/dt=200\text{A}/\mu\text{s}, T_J=125^{\circ}\text{C}$		34		ns
I_{RRM}	Max. Reverse Recovery Current			7		A
Q_{rr}	Reverse Recovery Charge			112		nC
t_{rr}	Reverse Recovery Time	$I_F=10\text{A}, V_R=100\text{V}, di_F/dt=500\text{A}/\mu\text{s}, T_J=125^{\circ}\text{C}$		29		ns
I_{RRM}	Max. Reverse Recovery Current			13		A
Q_{rr}	Reverse Recovery Charge			200		nC



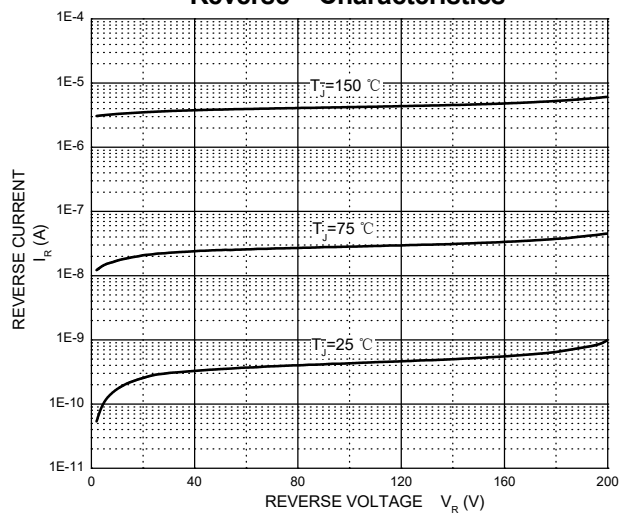
Reverse Recovery Waveform and Definitions

Typical Characteristics

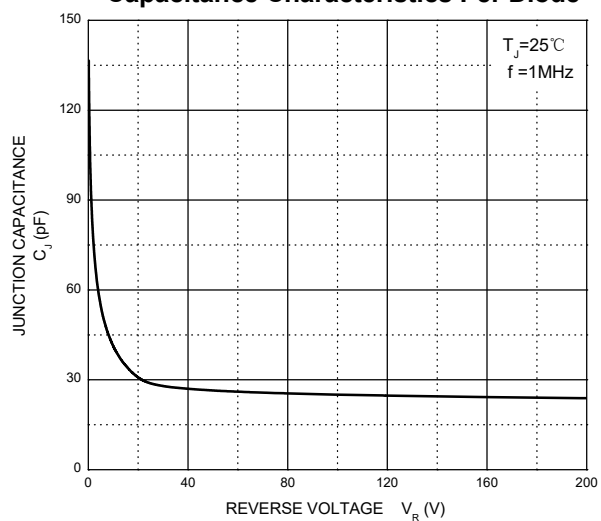
Forward Characteristics



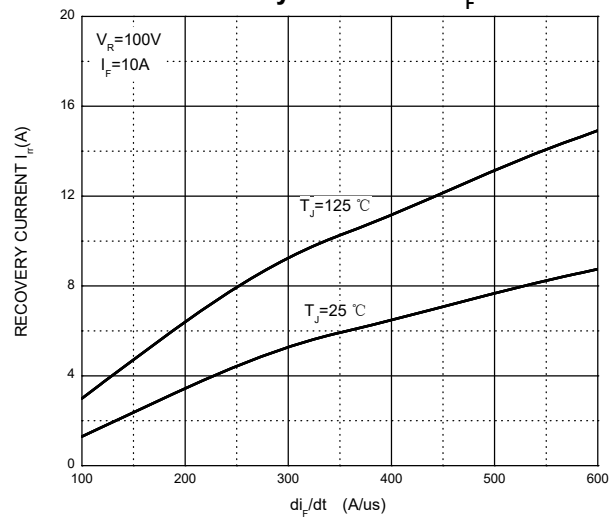
Reverse Characteristics



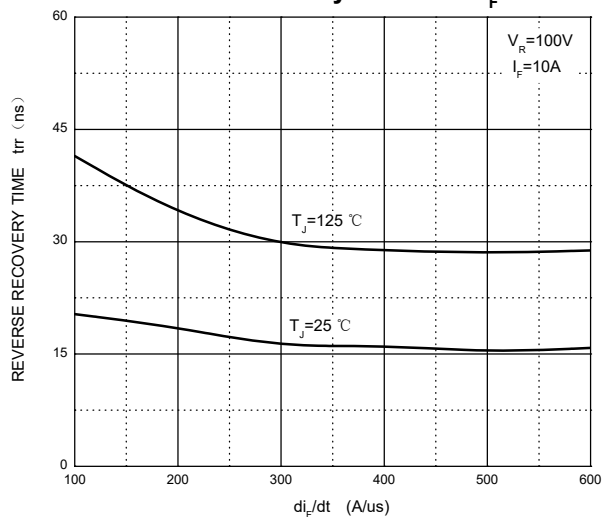
Capacitance Characteristics Per Diode



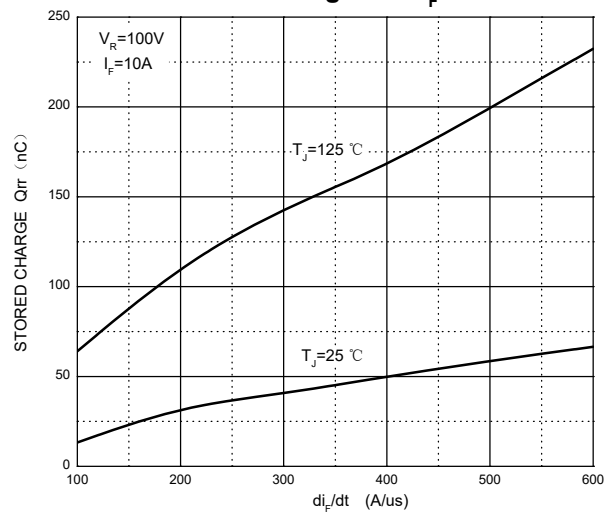
Recovery Current vs. di_F/dt



Reverse Recovery Time vs. di_F/dt

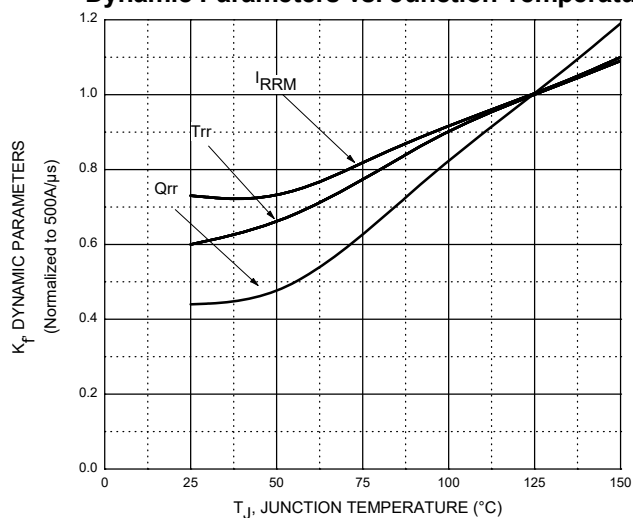


Stored Charge vs. di_F/dt

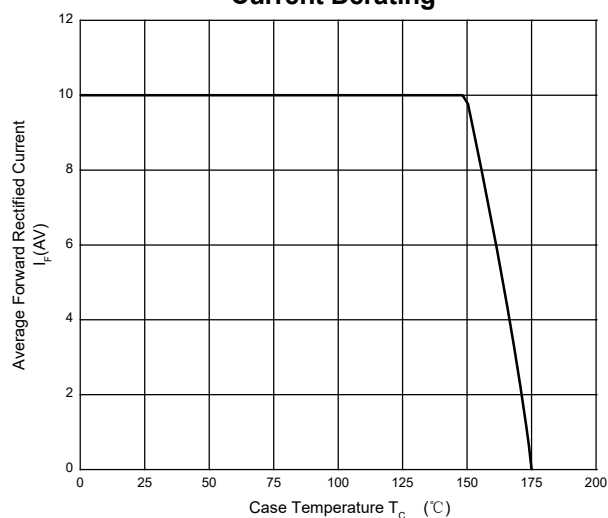


Typical Characteristics

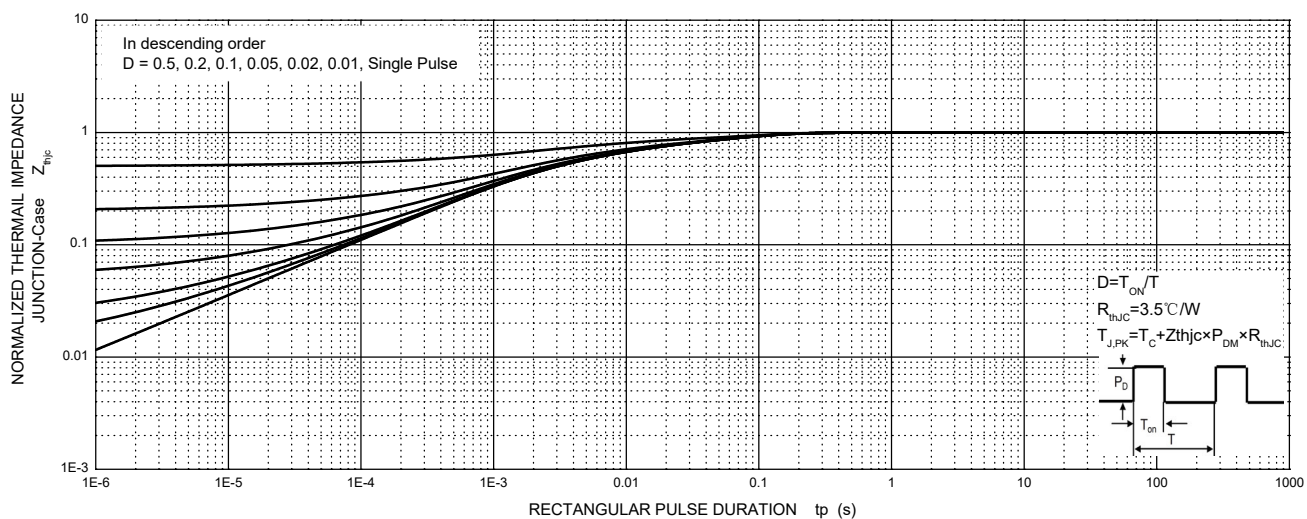
Dynamic Parameters vs. Junction Temperature



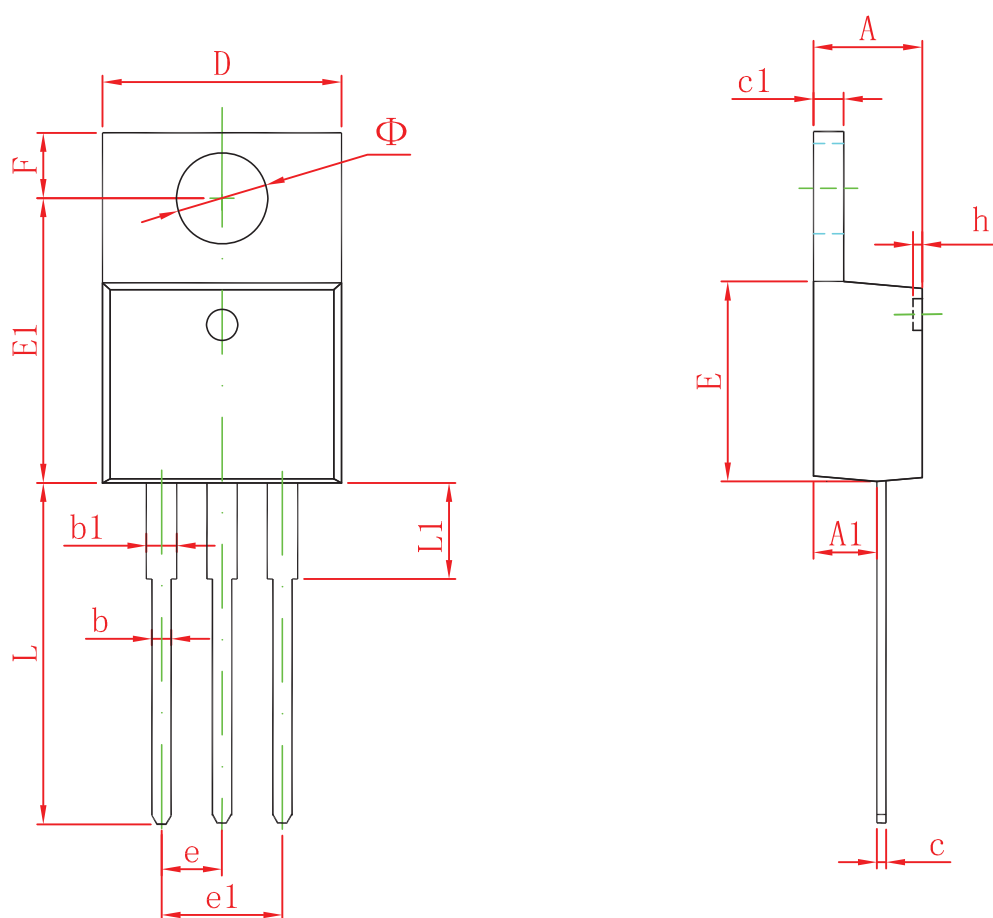
Current Derating



MUR20H20CT Transient Thermal Impedance, Junction-Case



TO-220-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.450	4.750	0.175	0.187
A1	2.520	2.820	0.099	0.111
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.300	0.500	0.012	0.020
c1	1.170	1.370	0.046	0.054
D	9.830	10.330	0.387	0.407
E	8.500	8.900	0.335	0.350
E1	12.050	12.650	0.474	0.498
e	2.540 TYP		0.100 TYP	
e1	4.900	5.200	0.192	0.205
F	2.540	2.940	0.100	0.116
h	0.100 TYP		0.004 TYP	
L	13.300	13.800	0.523	0.543
L1	3.540	3.940	0.139	0.155
Φ	3.735	3.935	0.147	0.155

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